

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









## **ULTRAFAST SOFT RECOVERY RECTIFIER DIODE**

#### **PRODUCT APPLICATIONS**

- Anti-Parallel Diode

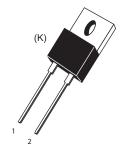
   Switchmode Power Supply
   Inverters
- Free Wheeling Diode
   -Motor Controllers
   -Converters
- -Inverters
   Snubber Diode
- PFC

### **PRODUCT FEATURES**

- Ultrafast Recovery Times
- Soft Recovery Characteristics
- Popular TO-220 Package
- Low Forward Voltage
- Low Leakage Current
- Avalanche Energy Rated

#### **PRODUCT BENEFITS**

- Low Losses
- Low Noise Switching
- Cooler Operation
- · Higher Reliability Systems
- Increased System Power Density





- 1 Cathode
- 2 Anode Back of Case - Cathode

#### **MAXIMUM RATINGS**

All Ratings:  $T_C = 25$ °C unless otherwise specified.

Symbol	Characteristic / Test Conditions	APT15DQ60K(G)	UNIT	
V <sub>R</sub>	Maximum D.C. Reverse Voltage			
V <sub>RRM</sub>	Maximum Peak Repetitive Reverse Voltage	600	Volts	
V <sub>RWM</sub>	Maximum Working Peak Reverse Voltage			
I <sub>F(AV)</sub>	Maximum Average Forward Current (T <sub>C</sub> = 129°C, Duty Cycle = 0.5)	15		
I <sub>F(RMS)</sub>	RMS Forward Current (Square wave, 50% duty)	30	Amps	
I <sub>FSM</sub>	Non-Repetitive Forward Surge Current (T <sub>J</sub> = 45°C, 8.3ms)	110		
E <sub>AVL</sub>	Avalanche Energy (1A, 40mH)	20	mJ	
T <sub>J</sub> ,T <sub>STG</sub>	Operating and StorageTemperature Range	-55 to 175	- °C	
T <sub>L</sub>	Lead Temperature for 10 Sec.	300		

#### STATIC ELECTRICAL CHARACTERISTICS

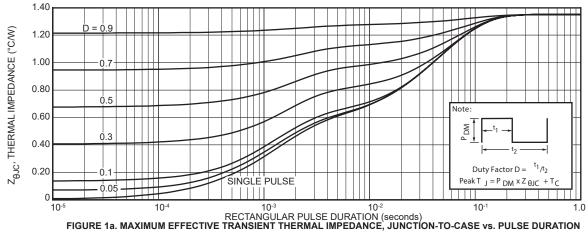
Symbol	Characteristic / Test Conditions		MIN	TYP	MAX	UNIT
V <sub>F</sub>	Forward Voltage	I <sub>F</sub> = 15A		2.0	2.4	
		I <sub>F</sub> = 30A		2.5		Volts
		I <sub>F</sub> = 15A, T <sub>J</sub> = 125°C		1.56		
I <sub>RM</sub>	Maximum Reverse Leakage Current	V <sub>R</sub> = 600V			25	- μΑ
		V <sub>R</sub> = 600V, T <sub>J</sub> = 125°C			500	
C <sub>T</sub>	Junction Capacitance, V <sub>R</sub> = 200V			25		pF

Symbol	Characteristic	Test Conditions	MIN	TYP	MAX	UNIT
t <sub>rr</sub>	Reverse Recovery Time $I_F = 1A$ , $di_F/dt = -100A/\mu s$ , $V_R = 30V$ , $T_J = 25$ °C		-	15		ns
t <sub>rr</sub>	Reverse Recovery Time	$I_F = 15A$ , $di_F/dt = -200A/\mu s$ $V_R = 400V$ , $T_C = 25^{\circ}C$	-	19		115
Q <sub>rr</sub>	Reverse Recovery Charge		-	21		nC
I <sub>RRM</sub>	Maximum Reverse Recovery Current		-	2	-	Amps
t <sub>rr</sub>	Reverse Recovery Time	$I_F = 15A$ , $di_F/dt = -200A/\mu s$ $V_R = 400V$ , $T_C = 125°C$	-	105		ns
Q <sub>rr</sub>	Reverse Recovery Charge		-	250		nC
I <sub>RRM</sub>	Maximum Reverse Recovery Current		-	5	1	Amps
t <sub>rr</sub>	Reverse Recovery Time	$I_F = 15A$ , $di_F/dt = -1000A/\mu s$ $V_R = 400V$ , $T_C = 125°C$	-	55		ns
Q <sub>rr</sub>	Reverse Recovery Charge		-	420		nC
I <sub>RRM</sub>	Maximum Reverse Recovery Current		-	15		Amps

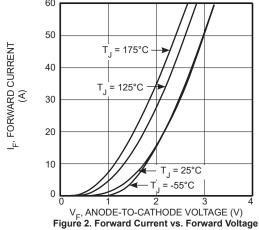
#### THERMAL AND MECHANICAL CHARACTERISTICS

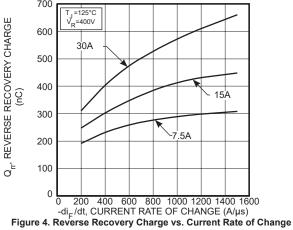
Symbol	Characteristic / Test Conditions	MIN	TYP	MAX	UNIT
R <sub>eJC</sub>	Junction-to-Case Thermal Resistance			1.35	°C/W
10/	Package Weight		0.07		oz
W <sub>T</sub>			1.9		g
Torque	Maximum Mounting Torque			10	lb•in
				1.1	N•m

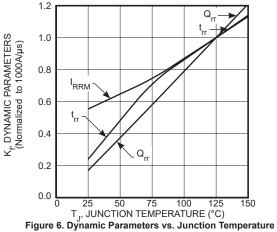
Microsemi reserves the right to change, without notice, the specifications and information contained herein.

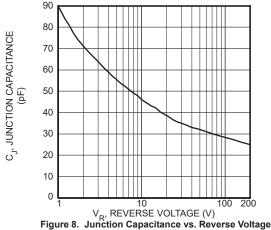


#### **TYPICAL PERFORMANCE CURVES**









#### APT15DQ60K(G)

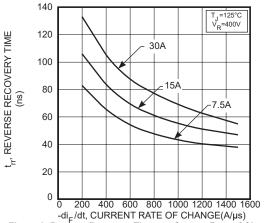
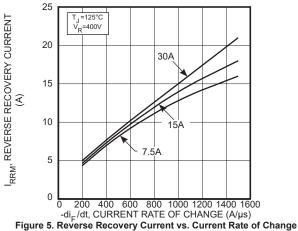


Figure 3. Reverse Recovery Time vs. Current Rate of Change



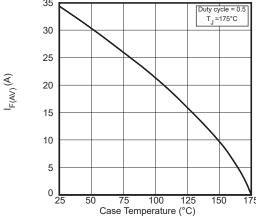


Figure 7. Maximum Average Forward Current vs. CaseTemperature

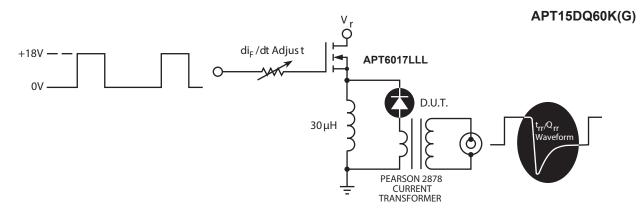


Figure 9. Diode Test Circuit

- 1 I<sub>F</sub> Forward Conduction Current
  2 di<sub>F</sub>/dt Rate of Diode Current Change Through Zero Crossing.
  3 I<sub>RRM</sub> Maximum Reverse Recovery Current
  4 t<sub>rr</sub> Reverse Recovery Time measured from zero crossing where diode current goes from positive to negative, to the point at
- $\bf 5 \ \, Q_{rr}$  Area Under the Curve Defined by  $\rm I_{RRM}$  and  $\rm t_{RR.}$

which the straight line through  $\rm I_{RRM}$  and 0.25,  $\rm I_{RRM}$  passes through zero.

Figure 10. Diode Reverse Recovery Waveform Definition

#### TO-220 (K) Package Outline e3 100% Sn

